Attorney Docket No.: 10541-1811

ASSIGNMENT DECORDATION COVER SHEET 02-12-2004 PATENTS ONLY PATENTS ONLY **TENTS** TO TH A 304 Please reco.

Name of Party(ies) conveying an interest: 102667812 copy thereof. 2. Name and Address of Party(ies) receiving an interest: William W. Sheng Terence J. Clark Visteon Global Technologies, Inc. Suite 728 Parklane Tower East James Fain 1 Parklane Blvd Sylvester Karpchuk Ronald P. Colino Dearborn, MI 48126 Additional name(s) and addresses attached? Additional name(s) of conveying party(ies) attached? ☐ Yes ☒ No ☐ Yes ☒ No Description of the interest conveyed: ☐ Change of Name Other: ☐ Security Agreement Merger Execution Date: 1/13/04; 1/21/04; 1/21/04; 1/28/04; 1/13/04 Application number(s) or patent number(s). Additional sheet attached? ☐ Yes ☒ No If this document is being filed together with a new application, the execution date of the application is: 1/27/04; 1/21/04; 1/21/04; 1/28/04; 1/27/04 B. Patent No.(s) A. Patent Application No.(s) 10771204 Additional numbers attached? Yes No Name and address of party to whom Number of applications and patents involved: 1 correspondence concerning document should be 7. Total fee (37 CFR 3.41) \$ 40.00 mailed: Enclosed Authorized to be charged to Deposit Account Robert K. Fergan No. 06-1500 (VISTEON GLOBAL **BRINKS HOFER GILSON & LIONE** TECHNOLOGIES, INC.) P.O. BOX 10395 Please charge any deficiencies in fee or credit any CHICAGO, IL 60610 overpayment to Deposit Account No. 06-1500. DO NOT USE THIS SPACE 10771204 02/11/2004 LMUELLER 00000097 061500 40.00 DA FC:8021 Statement and signature. To the best of my knowledge and belief, the foregoing information is true and correct and any attached copy is a true copy of the original document. Lobot & Frey Robert K. Fergan February 3, 2004 Name of Person Signing

Total number of pages including cover sheet, attachments, and document: 4

BRINKS HOFER GILSON &LIONE BRINKS HOFER GILSON & LIONE PO Box 10395

Chicago, IL 60611-5599

ASSIGNMENT

WHEREAS, we have invented: SILICON NITRIDE INSULATING SUBSTRATE FOR POWER SEMICONDUCTOR MODULE, identified as Visteon Disclosure No.: V202-0793 and Attorney Docket No.: 10541-1811, and described in the application executed on the same date hereof.

WHEREAS, VISTEON GLOBAL TECHNOLOGIES, INC., a corporation organized under the laws of the State of Michigan and located at Suite 728, Parklane Towers East, One Parklane Boulevard, Dearborn, Michigan 48126, is desirous of acquiring an exclusive right to said invention.

For valuable consideration, receipt of which is hereby acknowledged, we hereby sell and assign to VISTEON GLOBAL TECHNOLOGIES, INC., the full and exclusive right to said invention, to all patent applications for said invention in the United States and in all other countries, including all rights of priority in and to said invention in such other countries, and to all patents issued on said invention in the United States and in all other countries; and we hereby request the Director of the United States Patent and Trademark Office to issue all patents on said invention to VISTEON GLOBAL TECHNOLOGIES, INC, as the assignee.

Executed by:

Name	Signatu r e /	Date /
William W. Sheng		1/13/04
Terence J. Clark	7	
James Fain		
Sylvester Karpchuk		
Ronald P. Colino	Konald & Flut	1/13/04

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Executed by:

Name	Signature	Date
William W. Sheng		
Terence J. Clark	Telence 1. Clark	1/21/04
James Fain	James Clain	1/21/04
Sylvester Karpchuk		
Ronald P. Colino		407.00

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Executed by:

RECORDED: 02/03/2004

Name	Signature	Date
William W. Sheng		
Terence J. Clark		
James Fain	·	
Sylvester Karpchuk	Syller Kurachl	1.28-04
Ronald P. Colino		

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PATENT REEL: 014962 FRAME: 0900